

# Next Generation Chalcogenide Glass for Active and Passive Applications

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The Future Photonics Hub  
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With particular thanks to:



Kevin Huang  
*CVD and 2D*



Khouler Khan  
*High Purity Glass*



Ioannis  
Zeimpekis  
*2D and  
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*Optoelectronic  
Devices*



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*Optical Fibre*



Nicos A  
*2D Materials  
and Devices*



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*Technical Support*



Ed Weatherby  
*Laboratory  
Infrastructure*



Andrea Ravagli  
*New Material  
Development*

and Ghadah Alzaidy, *Solar Cells*

# Outline

- Chalcogenide Glass - Introduction
- Glass Manufacture – Improving Foundations
- Improving Materials – Building for the Future
- Device Challenges – Current and Planned



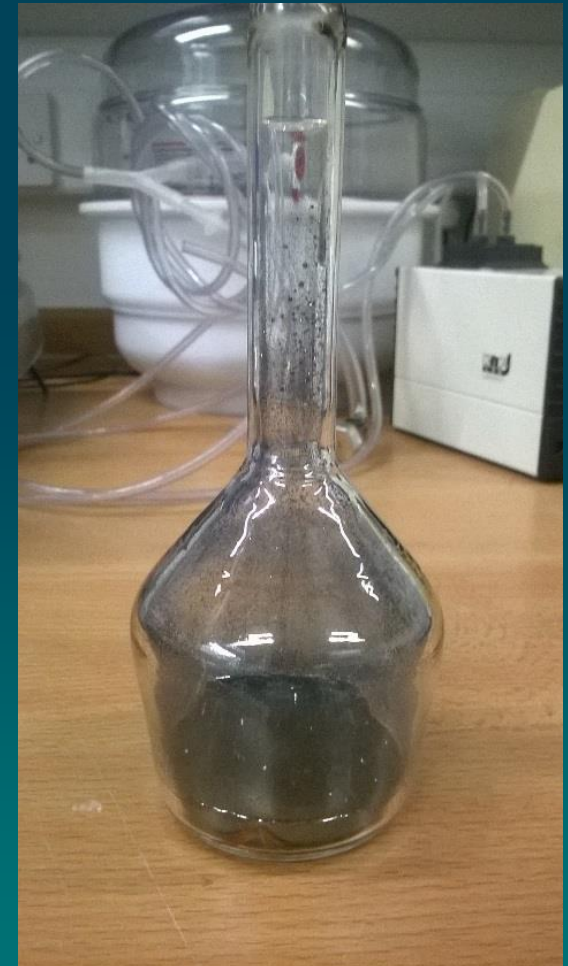
# Chalcogenide Glass Manufacture

- First Produced in 1950's
- Sealed Ampoule Techniques
- Driven by Defence Applications

Commercially Established

**SCHOTT**  
glass made of ideas

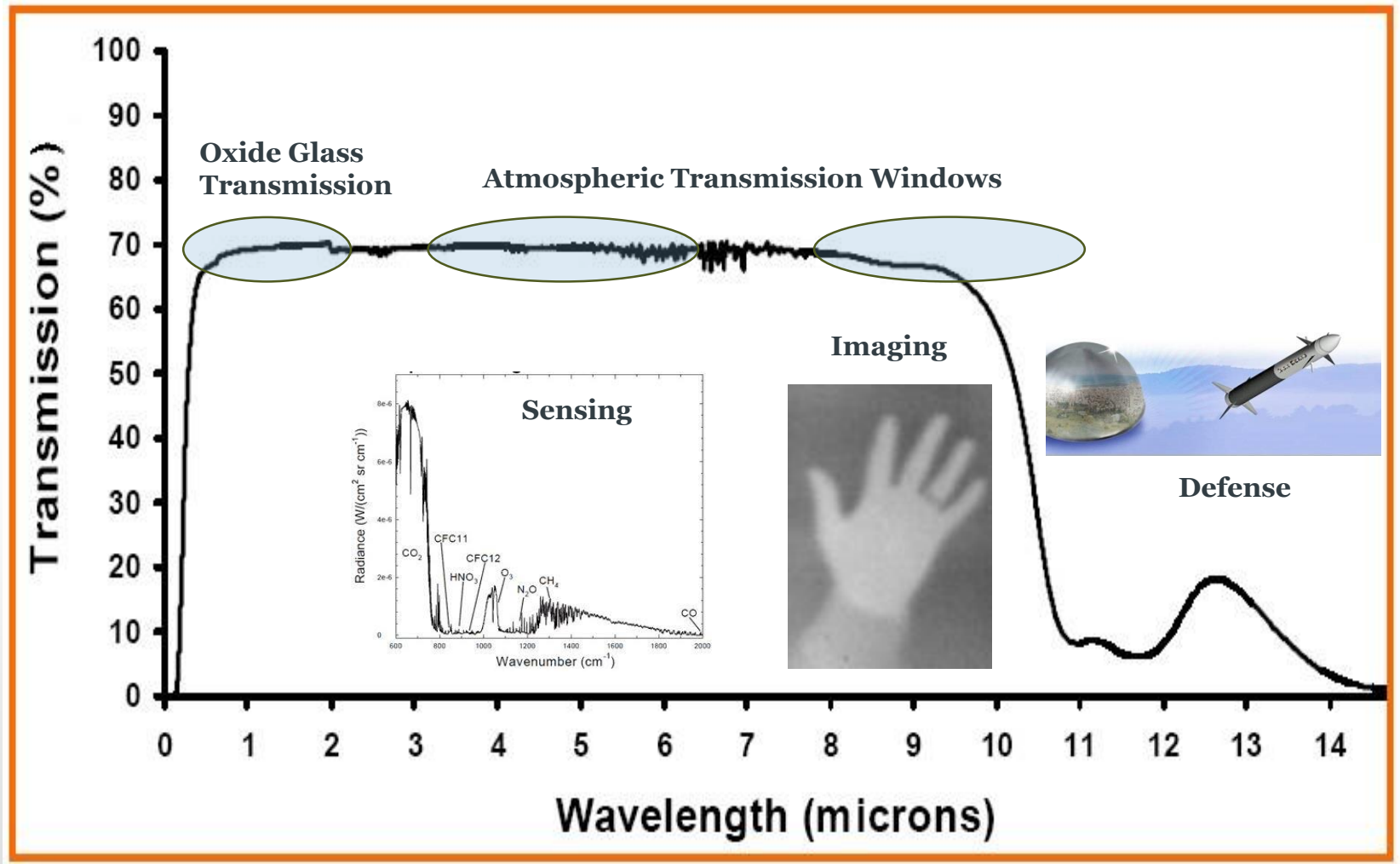
**umicore**



# Why are they Interesting?



# Initially – An IR Optical Material

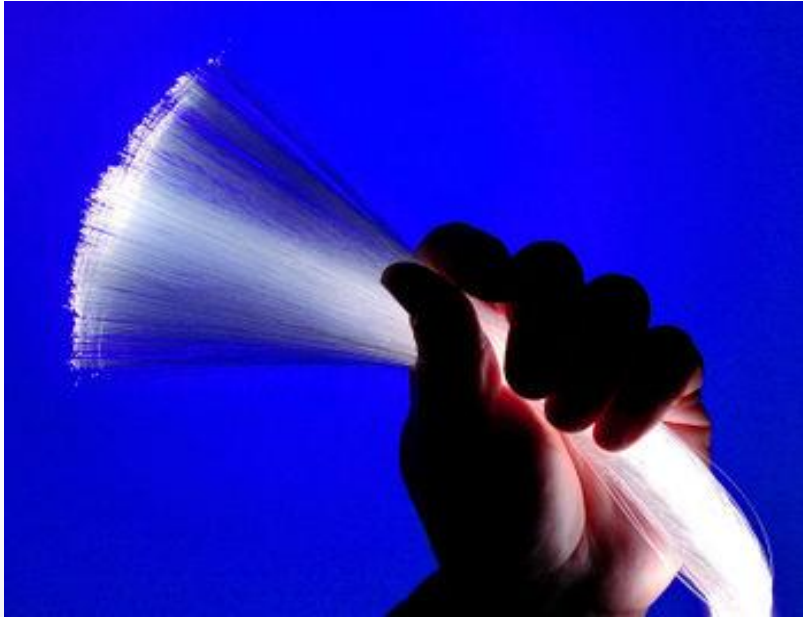




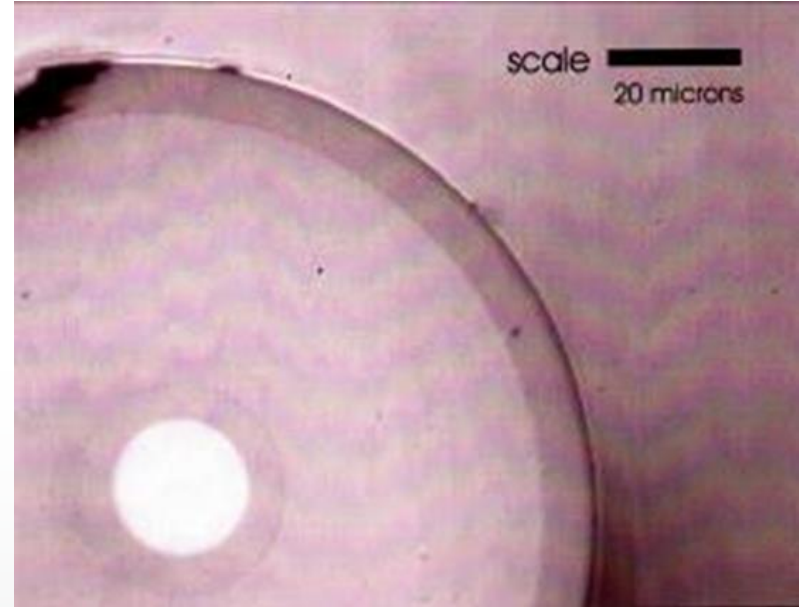
# Why more Materials Research?



# Glass Quality Far from Ideal



ORC Silica Fibre Fabrication  
Typical Loss:  $< 0.2$  dB/km



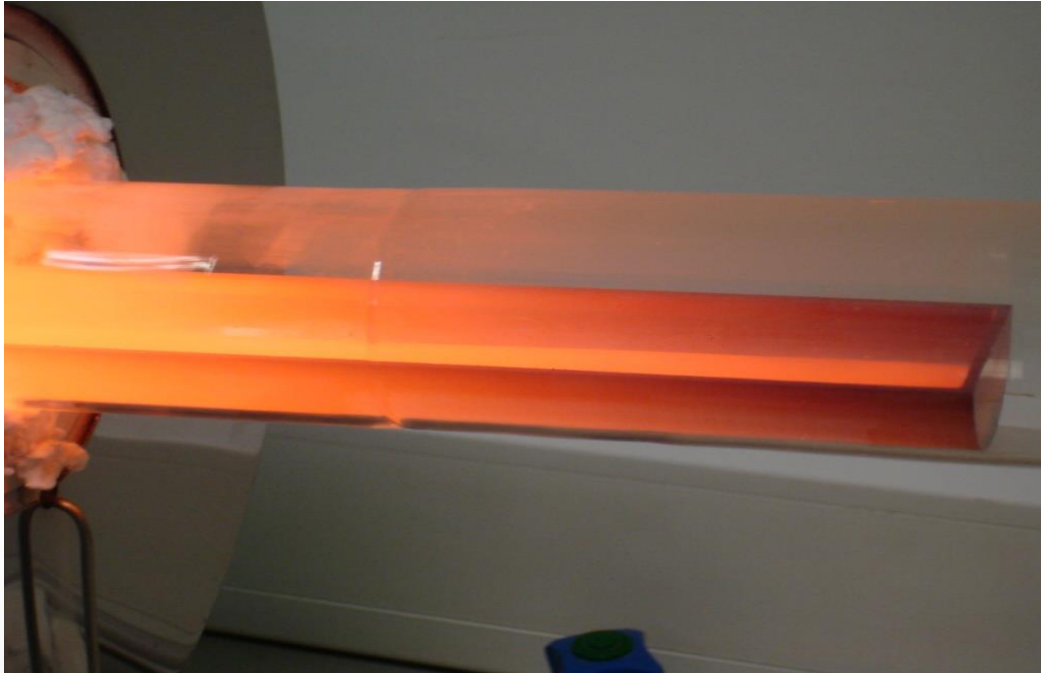
ORC Non-Silica Fibre Fabrication  
Typical Loss:  $< 2$  dB/m

**Ten Thousand Times Higher Loss**

**A radical change in glass preparation is needed!**



# Ga:La:S Melt Quenching



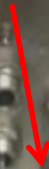
- Raw Materials batched in nitrogen purged glove box
- Sulphides melted in vitreous carbon crucibles
- Typically 24 hours at 1150°C in flowing argon
- Quenched to below glass transition temperature
- Annealed at 500°C, depending on ingot size

# Focus on Glass Melt Facility

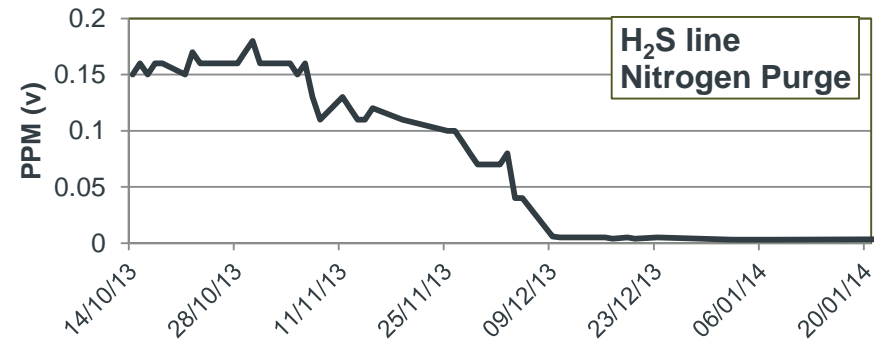
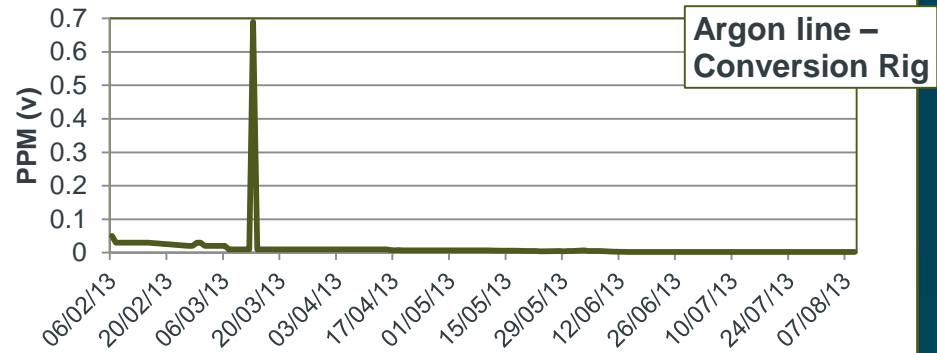
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Gas Inlet

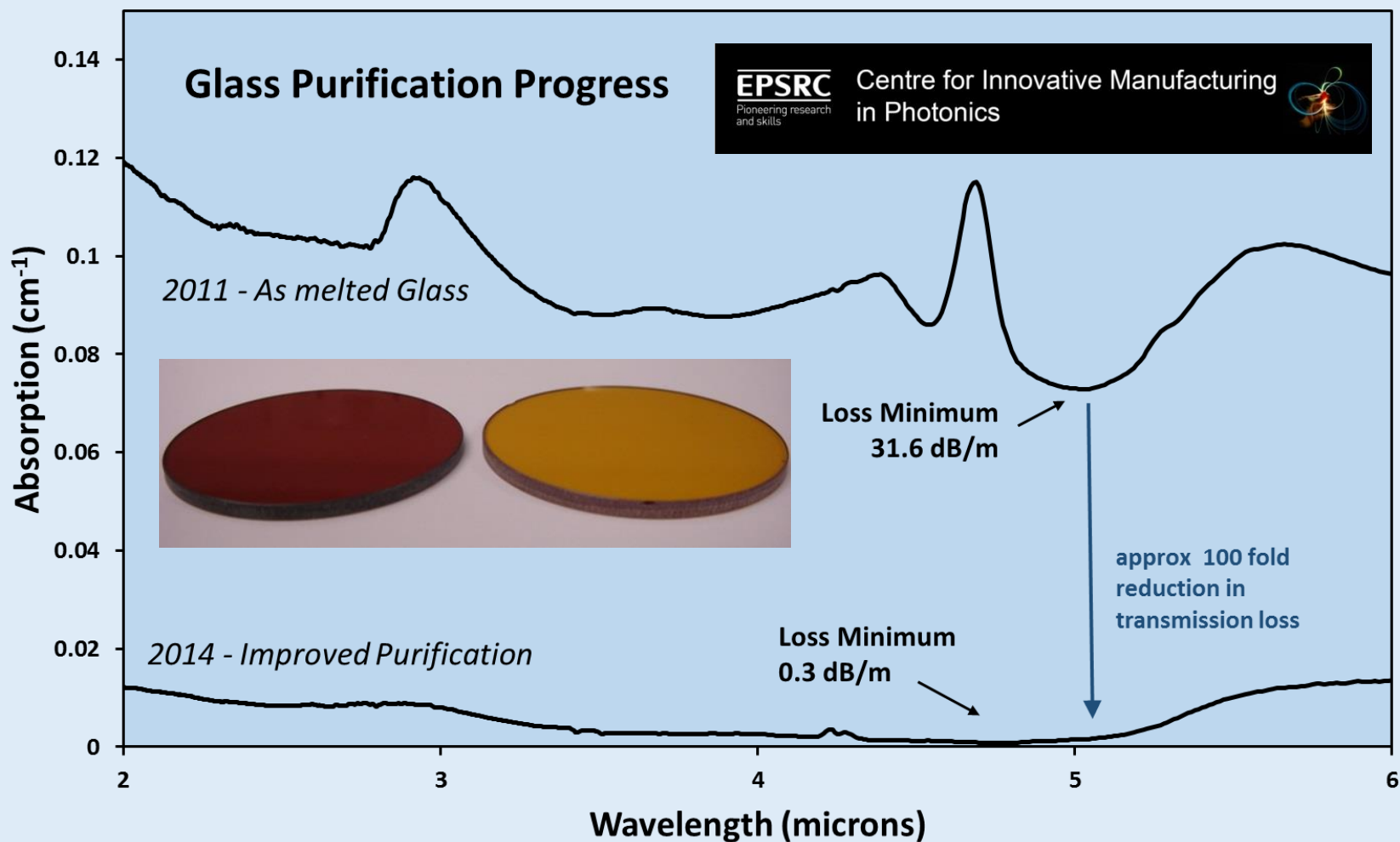


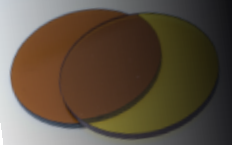
### Daily Monitoring of Gas Purity



Gas Purification

# Current Glass Purity





# ChAMP

Chalcogenide Advanced Manufacturing Partnership

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## GLS Infrared Transmitting Glass

A radically new chalcogenide glass and long-awaited alternative to toxic arsenic-based

- Optical transparency from the visible to infrared wavelengths and thermal stability up to 550°C
- Safer and more economical production; can be melted in a large-scale without the need for sealed ampoule processing
- Over 200 times greater performance and overall transmission in the 3-5 micron band as compared to early glasses of the same family; this is a result of substantially reduced impurity levels, in particular OH<sup>-</sup> and SH<sup>-</sup> absorption bands at around 3 and 4 microns
- A wide range of applications, e.g. IR and non-linear optics, high efficiency thin-film solar cells, high-capacity batteries and sensors with potential, as the choice semiconductor for developing beyond-CMOS electronics and all-optical processing technologies

### Physical data and typical characteristics

<b>OPTICAL</b>		
Refractive index @ 0.589 μm	2.493	
Zero material dispersion	4	μm
Temperature dependence dN/dT	75	x 10 <sup>-4</sup> / °C
Bulk transmission at 50% (1 mm thickness)	0.53 - 10.5	μm
Bulk absorption @ 4.8 μm	<0.001	cm <sup>-1</sup>
Damage threshold @ 1064 nm (coated)	>35	MW/cm <sup>2</sup>
Damage threshold @ 1.54 μm (uncoated)	>250	kW/cm <sup>2</sup>
<b>THERMAL</b>		
Glass transition	580	°C
Softening point	600	°C
Maximum use temperature	550	°C
Melting temperature	830	°C
Thermal expansion	10	°C <sup>-1</sup> x 10 <sup>-6</sup>
Specific heat capacity	0.54	J/g K
Thermal conductivity	0.43	W/ mK
<b>MECHANICAL</b>		
	4.04	g/cm <sup>3</sup>
	0.24	



### Standard formats

Available as bulk glass or polished optical components, thin and thick films and emerging as an optical fibre; dimensions for discs, rods, windows, prisms on request. Raw glass ingots (up to 500 grams) can be provided for your own in-house glass processing.

### Bespoke specifications

Specifications beyond the typical formats outlined here may be available, including:

- Raw glass ingots cut and polished to your specification
- Other glass compositions, which we can provide under standard material transfer agreement for rapid evaluation by industry and academia

Please contact us to discuss your specific requirements.

### Contact us

Professor Dan Hewak  
Optoelectronics Research Centre  
University of Southampton  
Southampton, UK

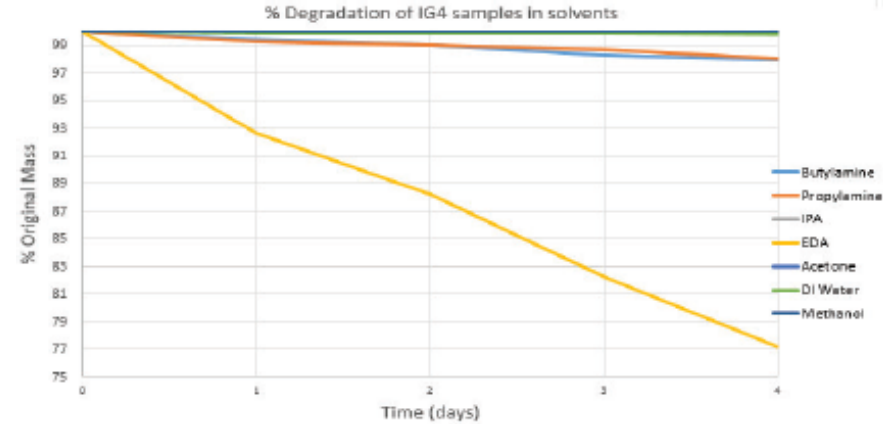
## Physical Data and Characteristics

Pick up a copy  
of our brochure

# Corrosion resistance

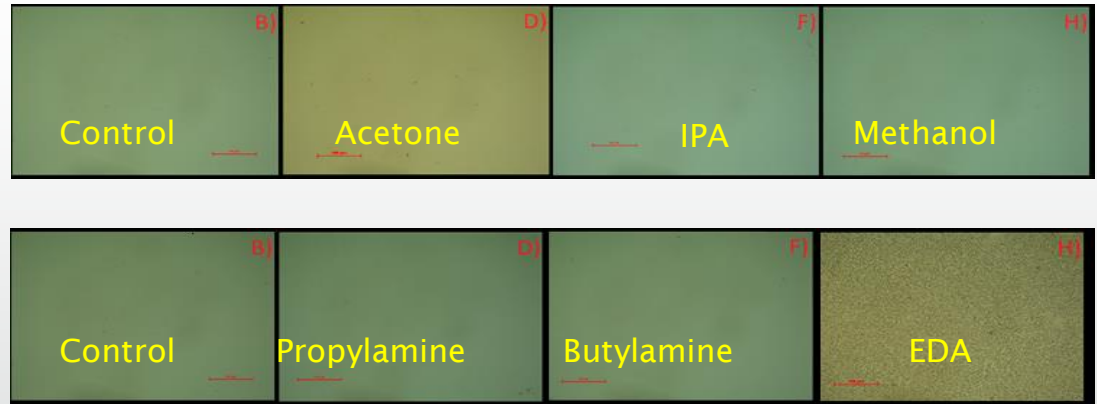
Chemical vulnerability weakness for previous chalcogenides

IG4 (Ge:As:Se) 4 day 23% mass loss in ethylenediamine (EDA)



- GLS surface after **1 month** exposure to

Cleaning Agents  
 Amine Solvents

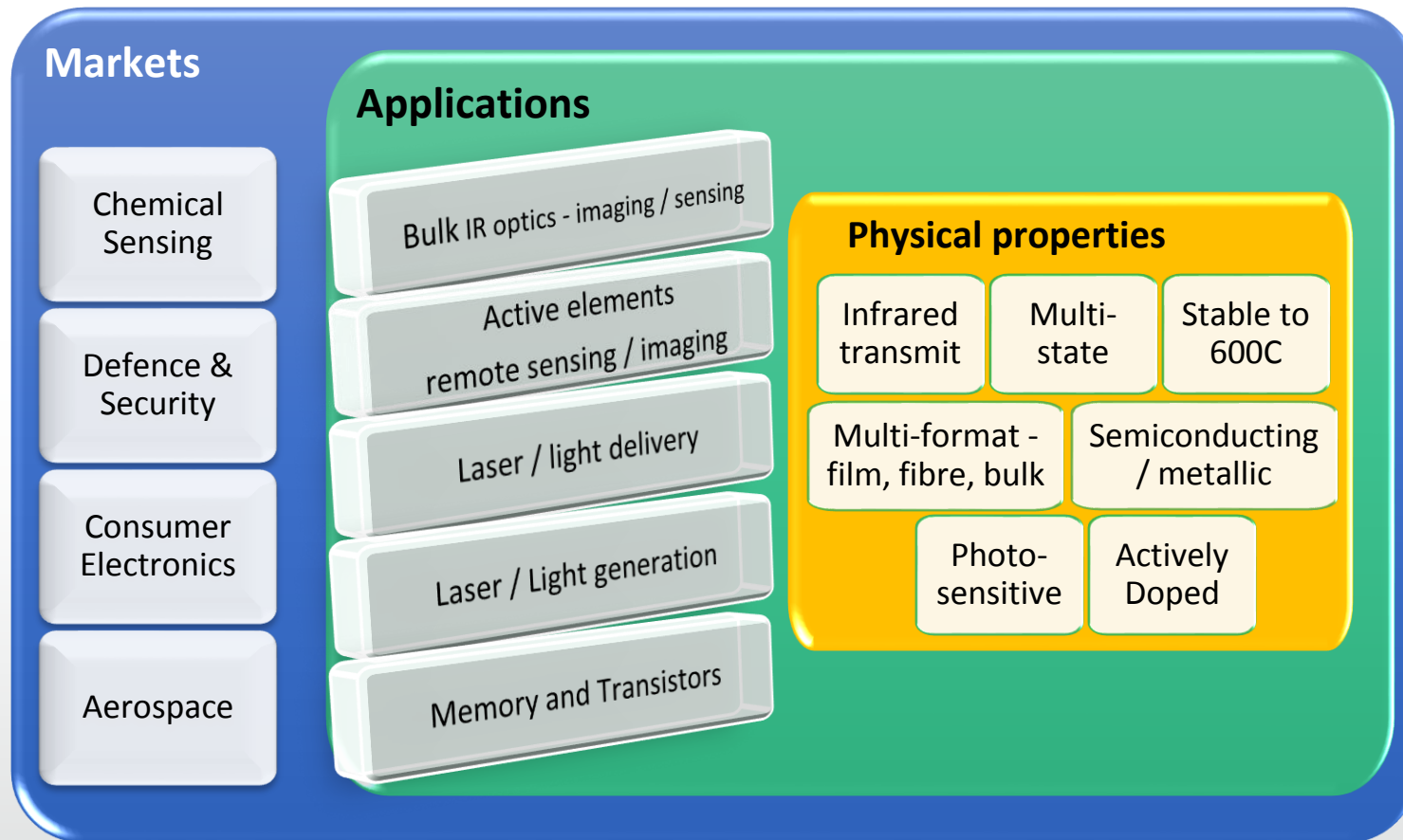


- Significantly improved chemical resistance

20X image surface



# Many Properties = Many Applications

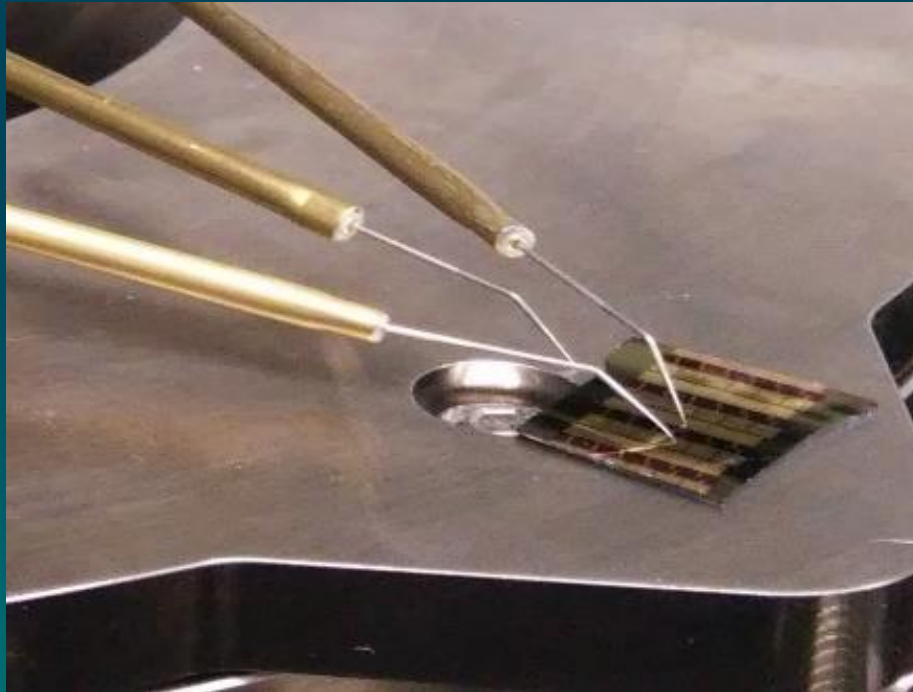


Chalcogenide content of systems will increase

slide courtesy of John Lincoln

# Emerging Devices

Demonstrated and Challenges:



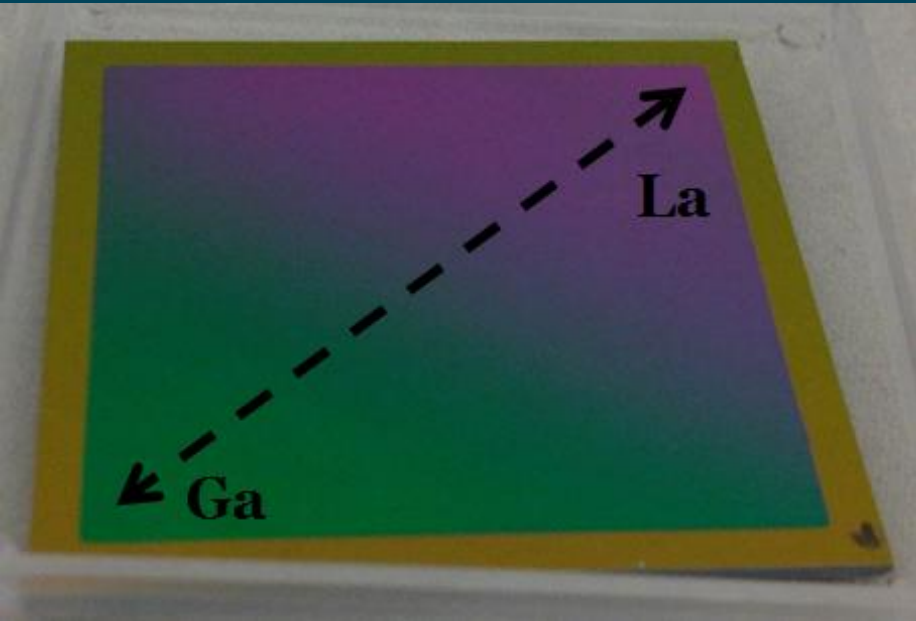


# Phase Change Memory

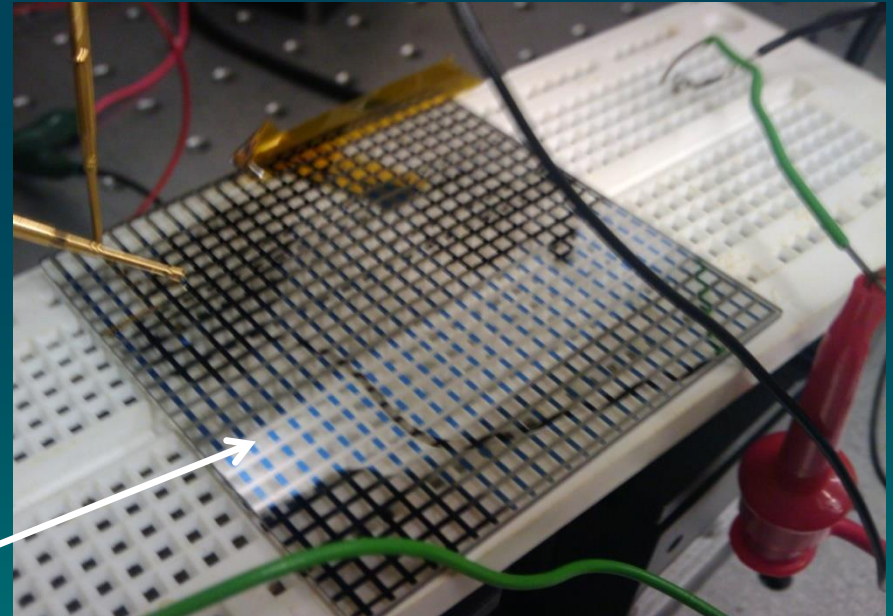
## High Throughput Screening Chip

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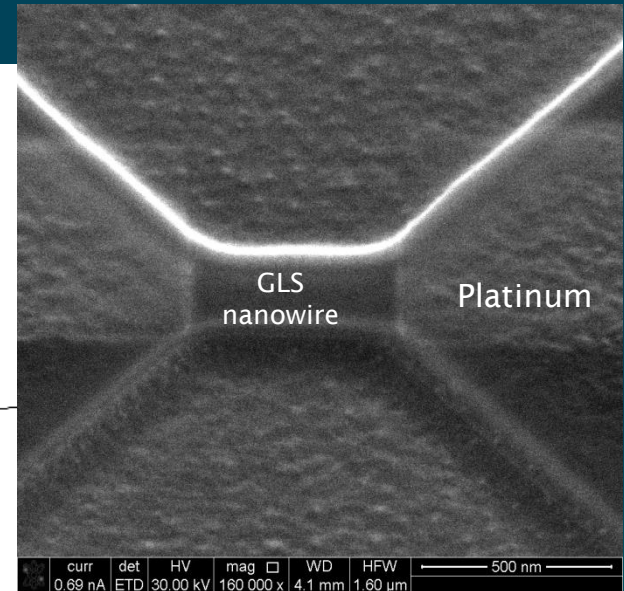
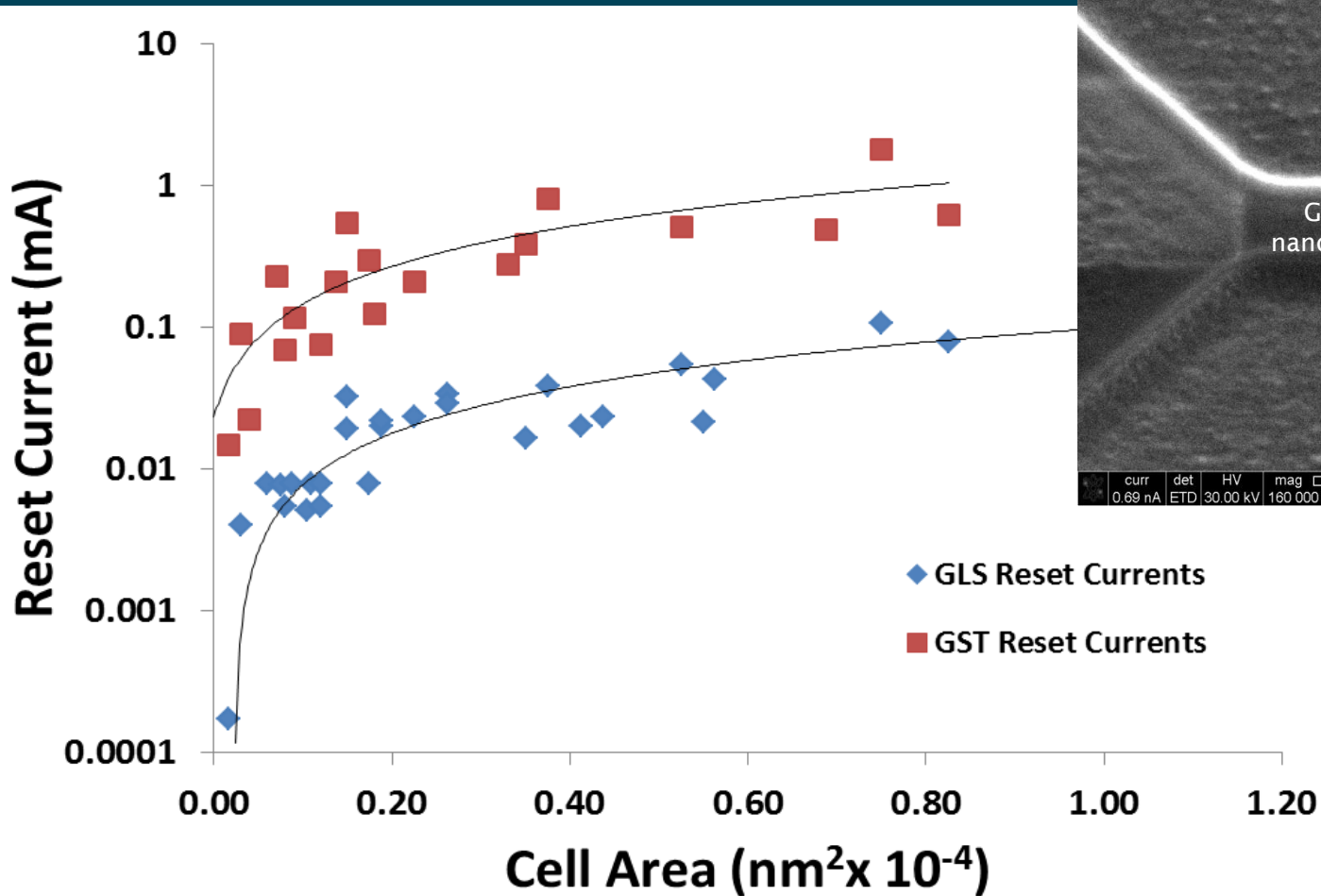
90% of Compositional Space



625 unique devices

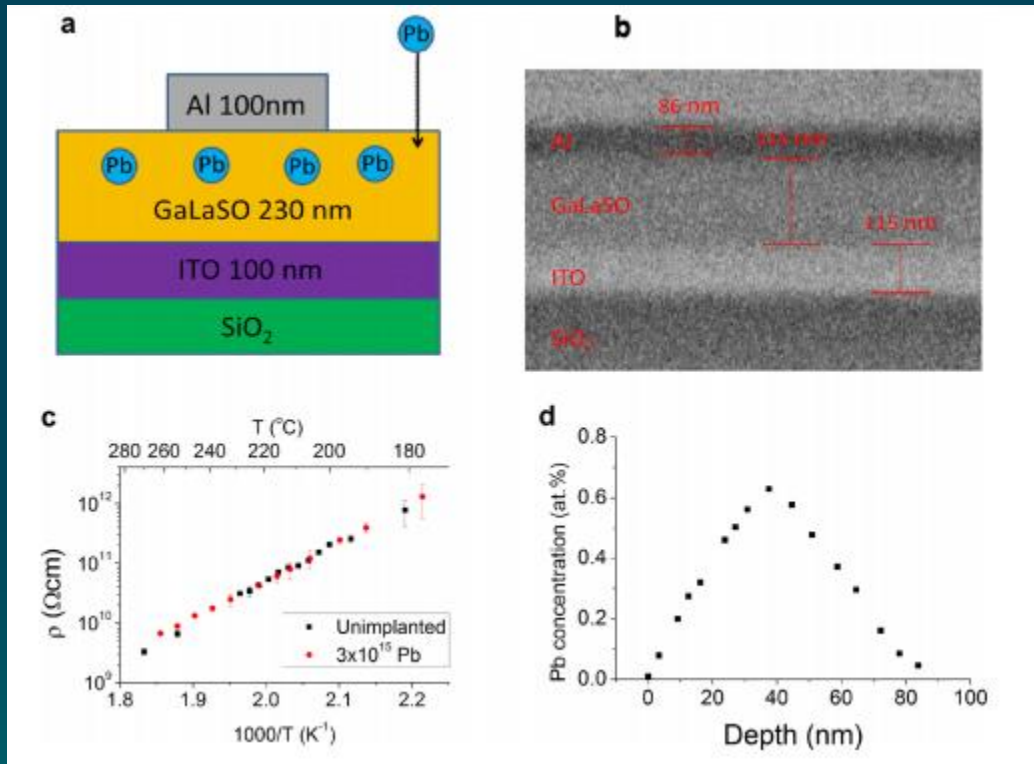
B.Gholipour, Novel Chalcogenide Optoelectronic and Nanophotonic Information Storage and Processing Devices, PhD Thesis - May 2012

# Optimum Composition GLS Switch





# Chalcogenide P/N Junction

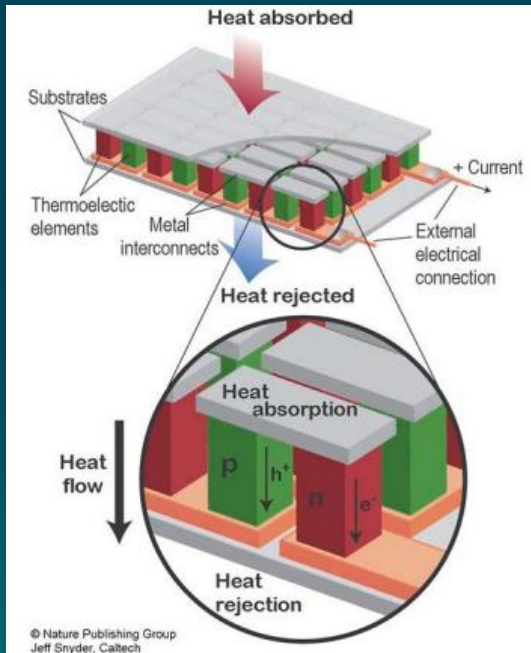


Modifying chalcogenides through non-equilibrium doping via ion implantation

(collaboration with Richard Curry, University of Surrey)

# Thermoelectric Devices

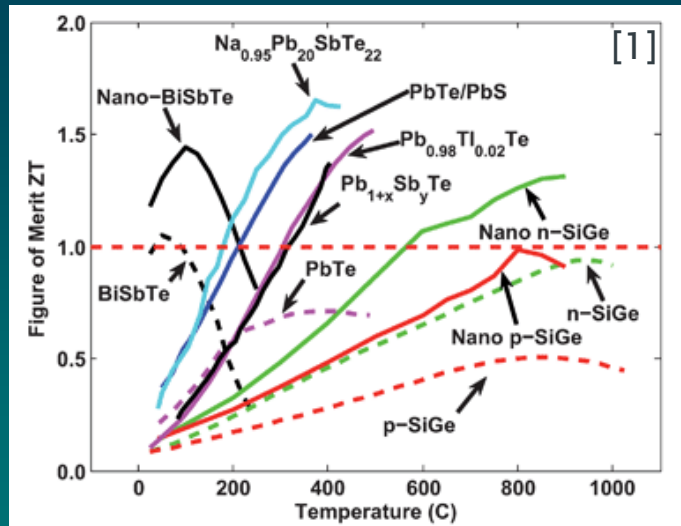
Waste Heat  $\rightarrow$  Electrical Power



Classical bulk TE

$$ZT = \frac{S^2 T}{\rho \lambda}$$

Figure of merit ( $ZT$ ) depends on Seebeck coefficient  $S$ , thermal conductivity  $\lambda$ , and electrical resistivity  $\rho$ .



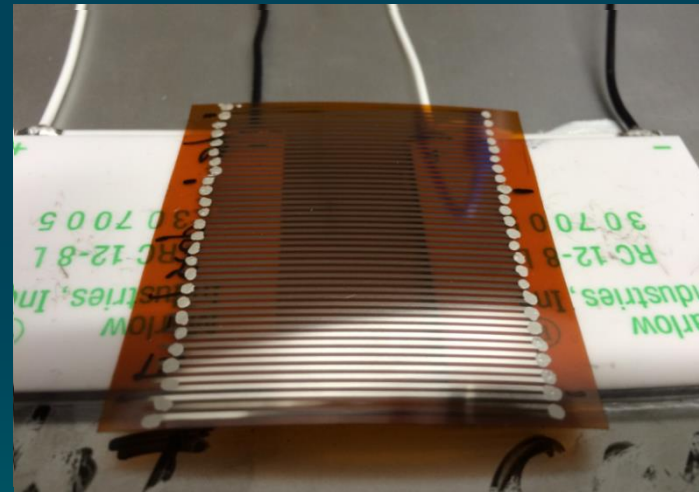
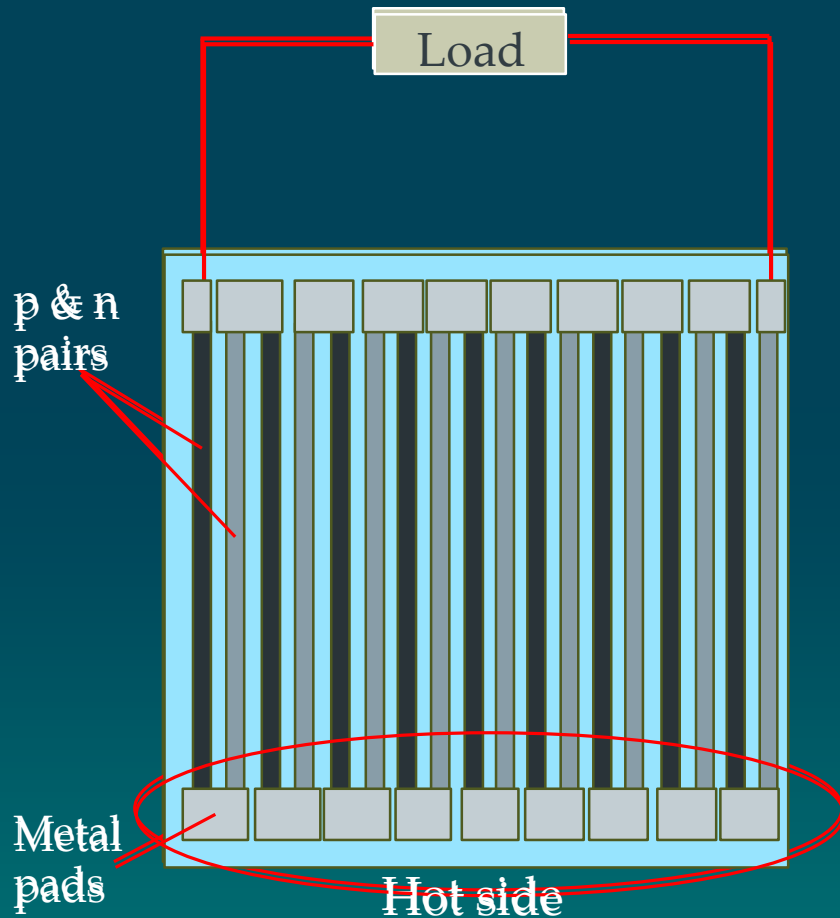
Research directions:

- Thin film TE
- Nanostructuring
- Novel design of TE

# Thermoelectric Device Fabrication

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Schematic and real device image of TFTE on PI substrate

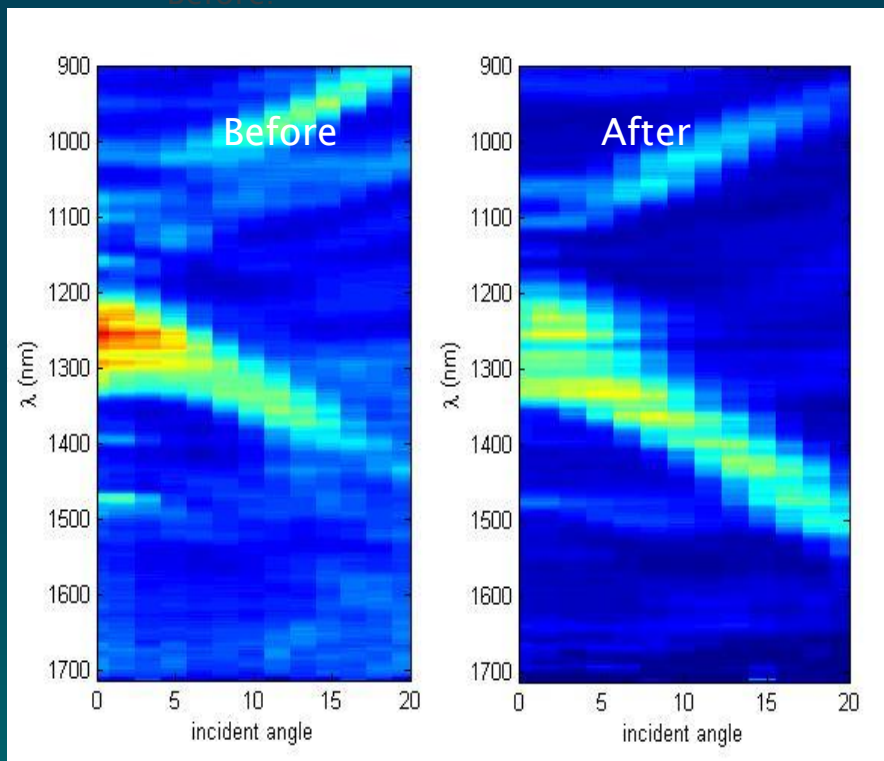
(collaboration with Harish Baskharim, University of Oxford)

# 3D Photonic Bandgap Structures

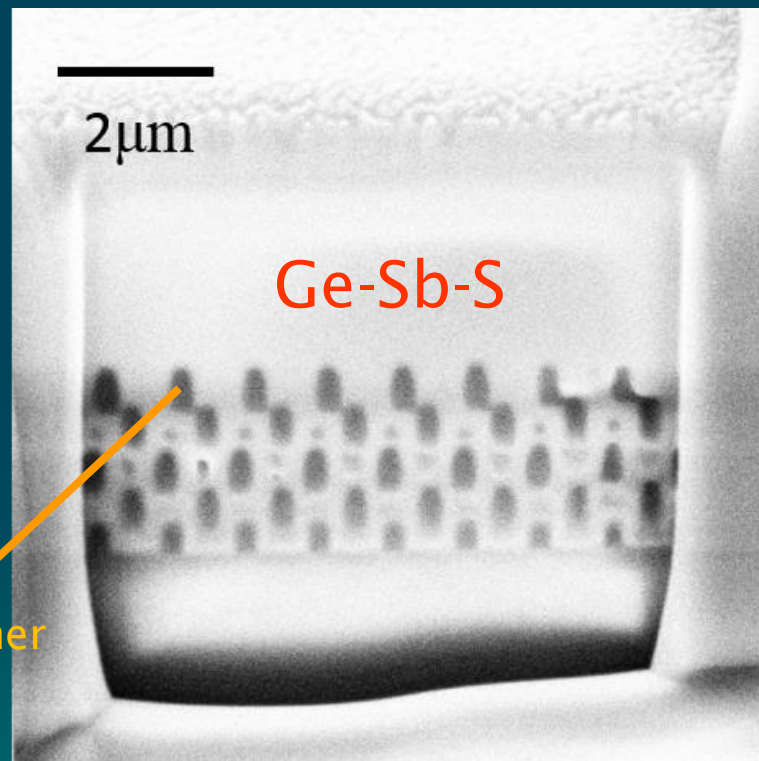
## Backfill with Ge-Sb-S by CVD

Before:

(a)



(b)



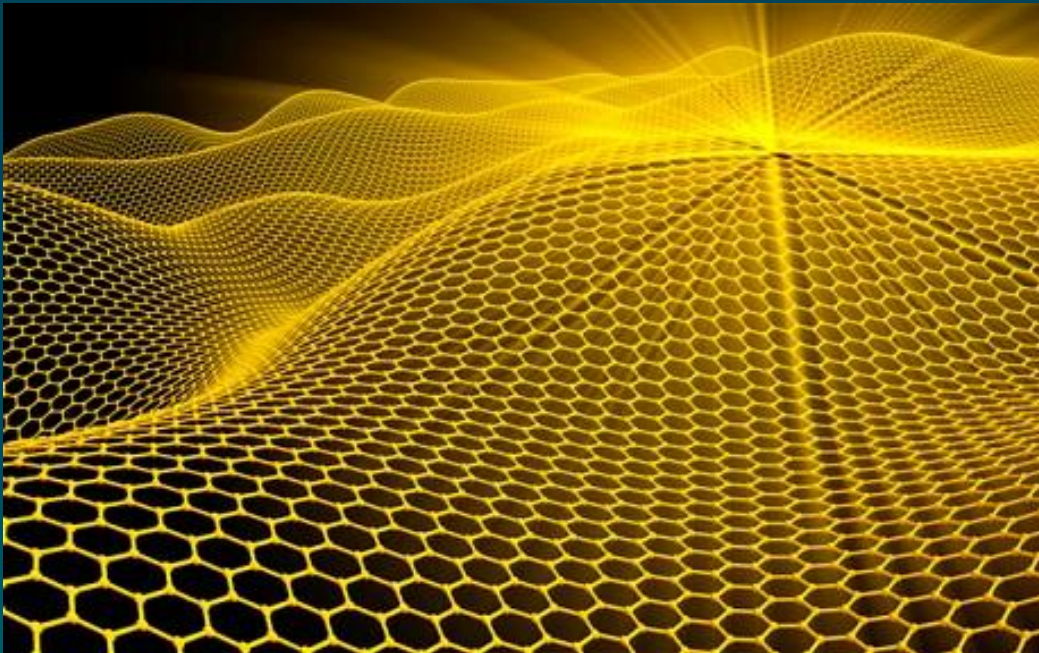
- (a) woodpile structure template before backfill process;
- (b) SEM image fabricated by FIB showing the quality of in-filling

Collaboration with John Rarity, University of Bristol)



# 2D Emerging Materials

## Applications and Challenges:

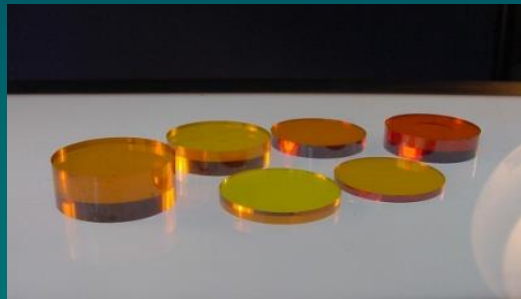


There remain hundreds of layered materials that could still yield monolayers



# Summary

- Chalcogenide glass clearly has broad reaching potential
- With long term funding radical changes in their processing and applications were enabled
- The fascinating application space ensures the future of these materials.
- If you'd like some glass or thin films, please ask!



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# Acknowledgements

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- |              |  |
|--------------|--|
| EP/J00278X/1 | FLITES : Fibre-Laser Imaging of gas Turbine Exhaust Species (ORC)        |
| EP/I019065/1 | Chalcogenide optoelectronic platform for next-generation optoelectronics |
| EP/H02607X/1 | EPSRC Centre for Innovative Manufacturing in Photonics                   |
| EP/G060363/1 | ChAMP – Chalcogenide Advanced Manufacturing Partnership                  |

More details at <http://chalcogenides.net>

